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TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSVII)

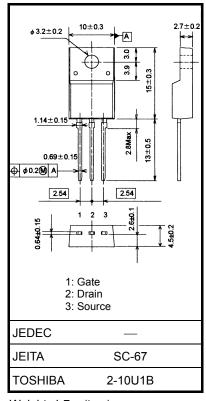
# TK8A60DA

### Switching Regulator Applications

- Low drain-source ON resistance:  $R_{DS}$  (ON) = 0.8  $\Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 4.0 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 600 \ V)$
- Enhancement-mode:  $V_{th} = 2.0$  to 4.0 V ( $V_{DS} = 10$  V,  $I_D = 1$  mA)

Character	ristics	Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	600	V	
Gate-source voltage		V <sub>GSS</sub>	±30	V	
Drain current	DC (Note 1)	ID	7.5	А	
	Pulse (Note 1)	I <sub>DP</sub>	30	~	
Drain power dissipati	on (Tc = 25°C)	PD	45	W	
Single pulse avalanch	ne energy (Note 2)	E <sub>AS</sub>	270	mJ	
Avalanche current		I <sub>AR</sub>	7.5	А	
Repetitive avalanche	energy (Note 3)	E <sub>AR</sub>	4.5	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature	range	T <sub>stg</sub>	-55 to 150	°C	

#### Absolute Maximum Ratings (Ta = 25°C)



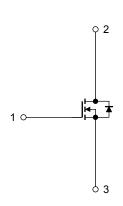
Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	2.78	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	62.5	°C/W

Internal Connection



Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V\_DD = 90 V, T\_ch = 25 °C (initial), L = 8.4 mH, R\_G = 25  $\Omega$ , I\_AR = 7.5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Unit: mm

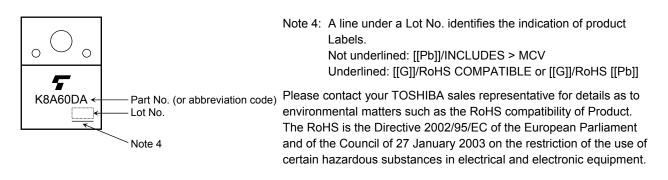
**Electrical Characteristics (Ta = 25°C)** 

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_		±1	μA
Drain cut-off current		I <sub>DSS</sub>	$V_{DS} = 600 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	600		_	V
Gate threshold ve	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	resistance	R <sub>DS (ON)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$		0.8	1.0	Ω
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$	1.0	4.0	_	S
Input capacitance		C <sub>iss</sub>			1050	_	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$		5	_	pF
Output capacitance		C <sub>oss</sub>			100		
Switching time	Rise time	tr	$I_D = 4 \text{ A } V_{OUT}$		25	_	
	Turn-on time	t <sub>on</sub>	$\begin{bmatrix} 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 $		60		ns
	Fall time	t <sub>f</sub>	 		10	_	
	Turn-off time	t <sub>off</sub>	Duty $\leq$ 1%, t <sub>w</sub> = 10 µs		75	_	
Total gate charge		Qg		_	20	_	
Gate-source charge		Q <sub>gs</sub>	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 7.5 \text{ A}$		13		nC
Gate-drain charge		Q <sub>gd</sub>	]	_	7		

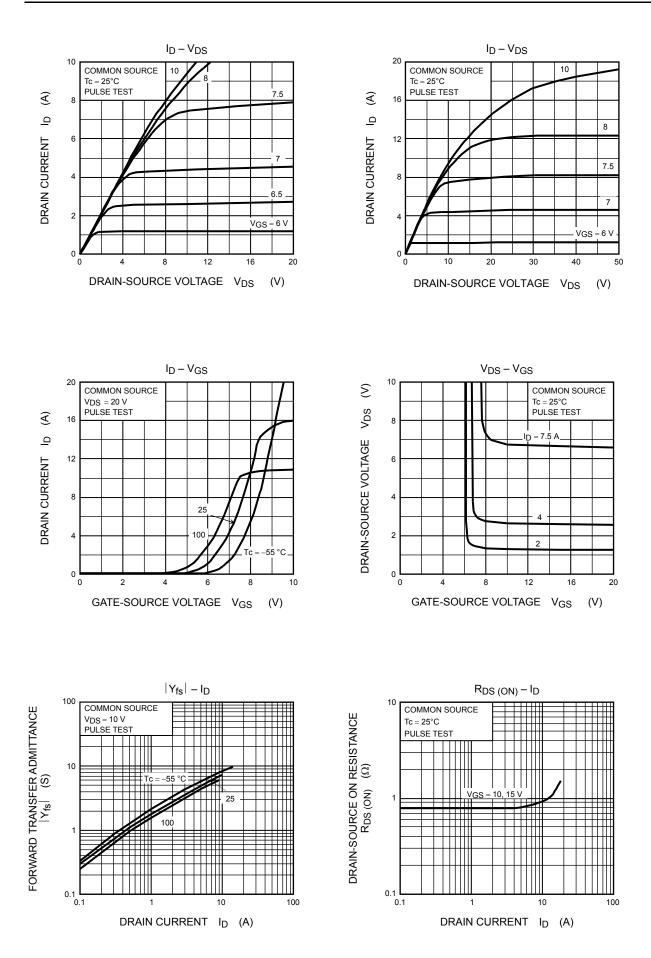
#### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	—	_	_	7.5	А
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	—	_	_	30	А
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 7.5 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 7.5 \text{ A}, V_{GS} = 0 \text{ V},$		1300		ns
Reverse recovery charge	Q <sub>rr</sub>	dl <sub>DR</sub> /dt = 100 A/μs		12		μC

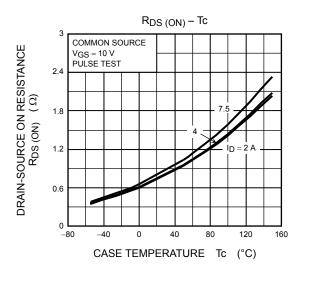
#### Marking

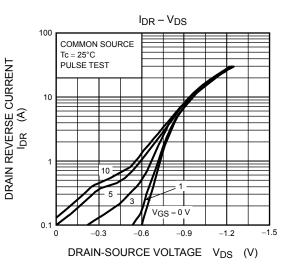


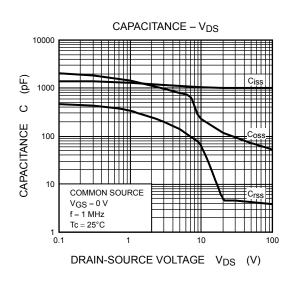
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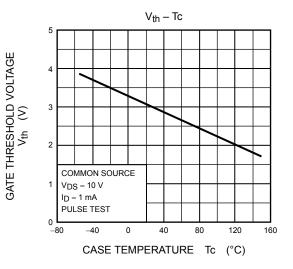


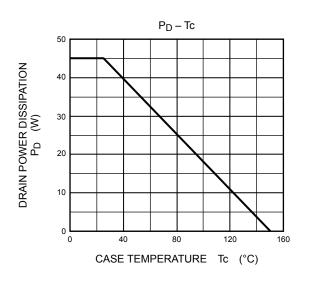
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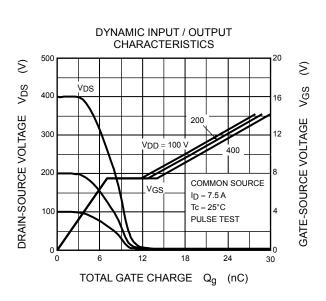


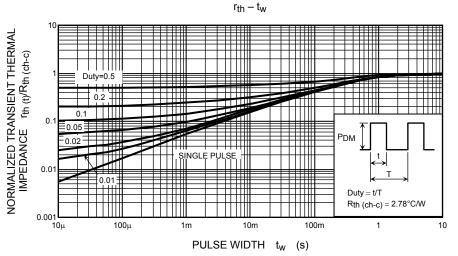


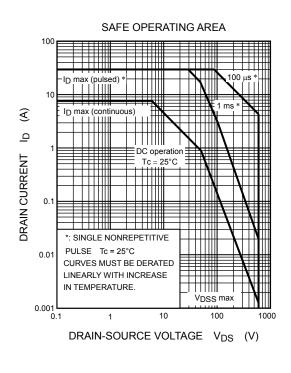


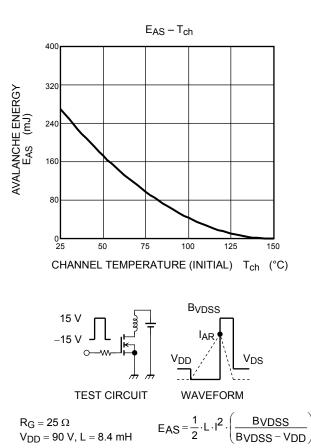












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